



Product Summary

BV _{DSS}	Rds(on) Max	I _D Max Ta = +25°C
-50V	10.0Ω @ V _{GS} = -5V	-174mA

Description and Applications

This MOSFET has been designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Motor Control
- Power Management Functions
- Backlighting

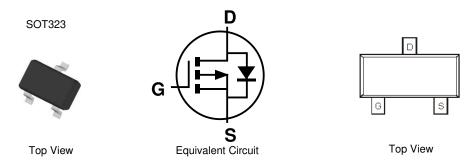
50V P-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42
 Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.006 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMP510DLW-7	SOT323	3000/Tape & Reel
DMP510DLW-13	SOT323	10000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

51D	ΥM

51D= Product Type Marking Code $\overline{Y}M = Date Code Marking$ Y or $\overline{Y} = Year (ex: H = 2020)$ M = Month (ex: 9 = September)

Date Code Key

Year	2017		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	E		Н	1	J	К	L	М	N	0	Р	R
	_				-					-	-	
					-					-		
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			V _{DSS}	-50	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current (Note 6) V _{GS} = -5V	ntinuous Drain Current (Note 6) $V_{GS} = -5V$ State $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$			-174 -139	mA
Maximum Continuous Body Diode Forward Curre	ls	-65	mA		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	%) (Note 6)	ldм	-1.0	A

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	320	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	398	°C/W
Total Power Dissipation (Note 6)		PD	470	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	273	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BVDSS	-50		-	V	V _{GS} = 0V, I _D = -250µA
Zero Gate Voltage Drain Current	IDSS	_		-1.0	μA	$V_{DS} = -50V, V_{GS} = 0V$
Gate-Source Leakage	lgss	_		±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	-0.8	_	-2.0	V	$V_{DS} = V_{GS}, I_D = -1mA$
Static Drain-Source On-Resistance	RDS(ON)	_		10	Ω	VGS = -5V, ID = -0.1A
Diode Forward Voltage	Vsd	_	-0.78	-1.5	V	VGS = 0V, IS = -100mA
DYNAMIC CHARACTERISTICS (Note 8)						·
Input Capacitance	Ciss	—	24.6	—	pF	
Output Capacitance	Coss	_	4.8	_	pF	V _{DS} = -25V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	2.8	-	pF	
Gate Resistance	Rg	-	2000	-	Ω	$f = 1.0MHz$, $V_{GS} = 0V$, $V_{DS} = 0V$
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	280	_	рС	
Total Gate Charge (V _{GS} = -10V)	Qg	-	560		рС	VGS = -4.5V, VDS = -10V,
Gate-Source Charge	Qgs	-	90		рС	I _D = -100mA
Gate-Drain Charge	Q _{gd}	_	77	-	рС	
Turn-On Delay Time	t _{D(ON)}	_	2.8	_	ns	
Turn-On Rise Time	tR	—	2.6	—	ns	V _{DD} = -30V, I _D = -0.27A,
Turn-Off Delay Time	tD(OFF)	—	11.1	—	ns	$R_{GEN} = 50\Omega$, $V_{GS} = -10V$
Turn-Off Fall Time	tF	_	7.2	_	ns	

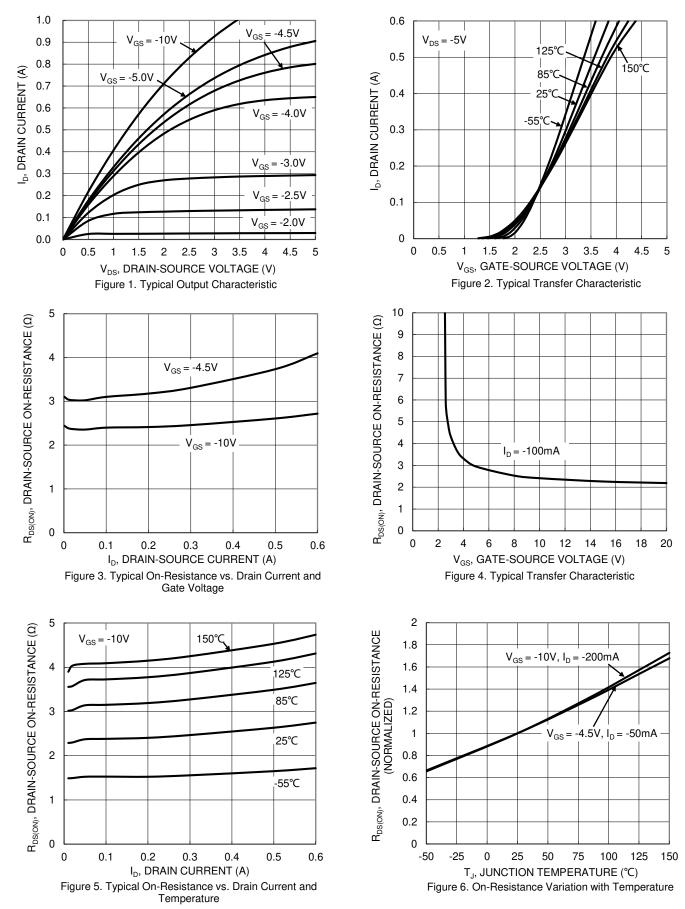
5. Device mounted on FR-4 PCB, with minimum recommended pad layout. Notes:

Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
 Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



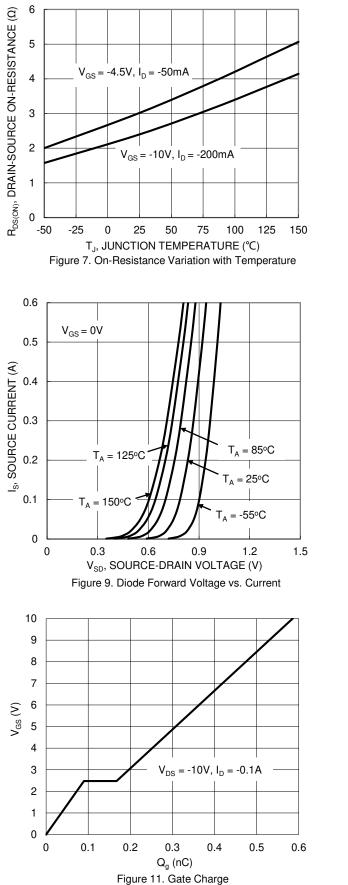
DMP510DLW

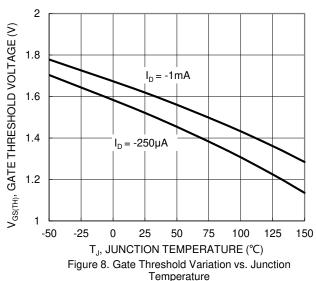


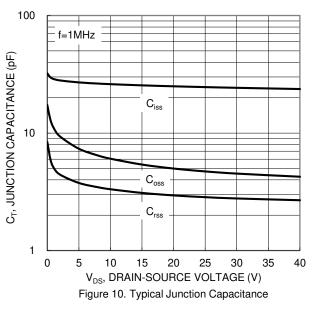
DMP510DLW Document number: DS40228 Rev. 2 - 2 February 2020 © Diodes Incorporated



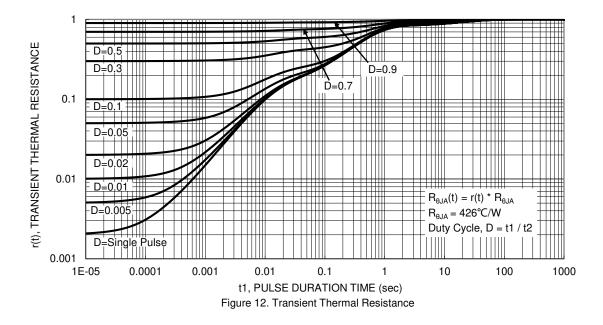
DMP510DLW







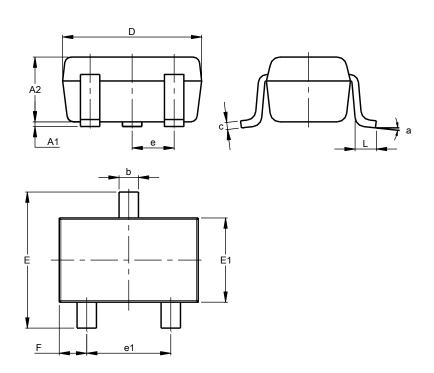






Package Outline Dimensions

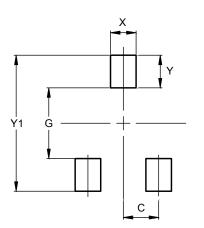
Please see http://www.diodes.com/package-outlines.html for the latest version.



	50	T323							
Dim									
			Тур						
A1	0.00	0.10	0.05						
A2	0.90	1.00	0.95						
b	0.25	0.40	0.30						
c	0.10	0.18	0.11						
D	1.80	2.20	2.15						
Е	2.00	2.20	2.10						
E1	1.15	1.35	1.30						
e	C).650 B	SC						
e1	1.20	1.40	1.30						
F	0.375	0.475	0.425						
1	0.25	0.40	0.30						
а	0°	8°							
All	Dimen	sions i	in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500

SOT323

SOT323



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